## SENSITRON SEMICONDUCTOR

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TECHNICAL DATA DATA SHEET 193, REV. C

# HERMETIC AXIAL LEAD / MELF SCHOTTKY BARRIER DIODE

DESCRIPTION: A 45 VOLT, 1.0 AMP, AXIAL LEAD/SURFACE MOUNT SCHOTTKY BARRIER DIODE.

#### **MAXIMUM RATINGS**

All ratings are at  $T_A = 25^{\circ}$ C unless otherwise specified.

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RATING	CONDITIONS	MIN	TYP	MAX	UNIT	
Peak Inverse Voltage (PIV)	←	1	-	45	Vdc	
Average DC Output Current (I <sub>o</sub> )	<b>↑</b>	-	-	1.0	Amps	
Peak Single Cycle Surge Current (I <sub>fsm</sub> )	t <sub>p</sub> = 8.3 ms Single Half Cycle Sine Wave, Superimposed On Rated Load	-	-	25	Amps(pk)	
Thermal Resistance ( <sub>0,JL</sub> )	Junction to Lead d = 0.375"	ı	-	70	°C/W	
Thermal Resistance (θ <sub>JEC</sub> )	Junction to Endcap	-	-	40	°C/W	
Junction Temperature (T <sub>J</sub> )	-	-55	-	+125	°C	
Operating Temperature (T <sub>op)</sub>	-	-55	-	+125	°C	
Storage Temp. (T <sub>stg</sub> )	-	-55	-	+150	°C	

### **ELECTRICAL CHARACTERISTICS**

CHARACTERISTIC	CONDITIONS	MIN	TYP	MAX	UNIT
Maximum Forward Voltage (V <sub>f</sub> )	I <sub>F</sub> = 1.0A (300 μsec pulse, duty cycle < 2%)	-	-	0.49	Volts
Maximum Instantaneous Reverse Current At Rated (PIV)	T <sub>A</sub> = 25° C T <sub>A</sub> = 100° C	-	-	0.05 4.0	μAmps mAmps
Junction Capacitance (C <sub>J</sub> )	$\begin{aligned} &V_R = 5 \text{ Vdc} \\ &0.01 \leq f \leq 1 \text{MHz} \\ &V_{sig} = 15 \text{ mV p-p} \end{aligned}$	-	-	70	pF

**Notes:** - All ratings are at TA = 25°C unless otherwise specified.

- Maximum storage temperature range: -55°C to +150°C.
- Maximum operating temperature range: -55°C to +125°C (1N5819-1, 1N5819UR-1).
- $\leftarrow$  Derate linearly at 4.5 V/°C above T<sub>L</sub> or T<sub>EC</sub> = +100°C (1N5819-1), where T<sub>EC</sub> is at L = .375 inch.
- $\uparrow$  Derate linearly at 14 mA/°C above T<sub>L</sub> or T<sub>EC</sub> = +55°C (1N5819-1), where T<sub>EC</sub> is at L = .375 inch.

<sup>• 221</sup> West Industry Court Deer Park, NY 11729-4681 Phone (631) 586 7600 Fax (631) 242 9798 •

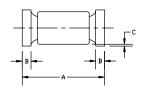
<sup>•</sup> World Wide Web - www.sensitron.com • E-mail Address - sales@sensitron.com •

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**AXIAL** 









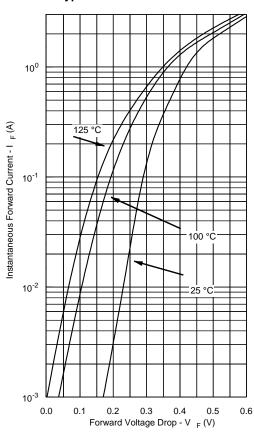
SCHOTTKY BARRIER 1N5819-1

PACKAGE	DIMENSIONS - INCHES (MILLIMETERS)			
STYLE	φВ	φD	G	L
	.028/.034	.08/.107	.160/.205	1.00/1.30
DO-41	0.71/0.86	.203/.272	.406/.521	2.54/3.302

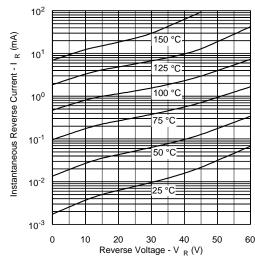
SCHOTTKY BARRIER 1N5819UR-1

PACKAGE	DIMENSIONS - INCHES (MILLIMETERS)			
STYLE	Α	В	С	D
	.189/.205	.016/.022	0.001 Min	.094/.105
DO-213AB	.480/.521	0.41/0.56	0.03 Min	2.39/2.67

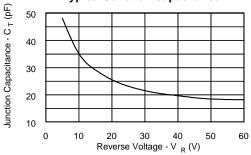
### **Typical Forward Characteristics**



### **Typical Reverse Characteristics**



#### **Typical Junction Capacitance**



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